RT1N150X SERIES

〈Transistor〉

Transistor With Resistor

For Switching Application

Silicon NPN Epitaxial Type

DESCRIPTION

RT1N150X is a one chip transistor
with built-in bias resistor,PNP type is RT1P150X.

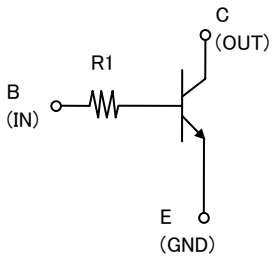
FEATURE

・Built-in bias resistor (R1=100kΩ).

APPLICATION

Inverted circuit,switching circuit,interface circuit,driver circuit.

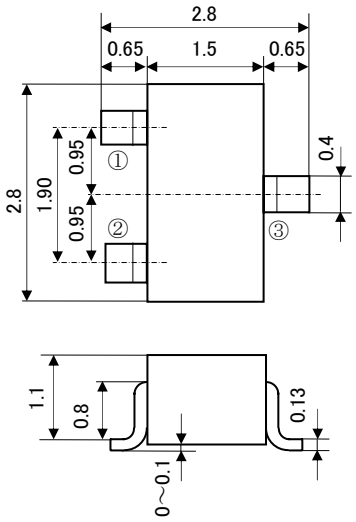
Equivalent circuit



OUTLINE DRAWING

UNIT : mm

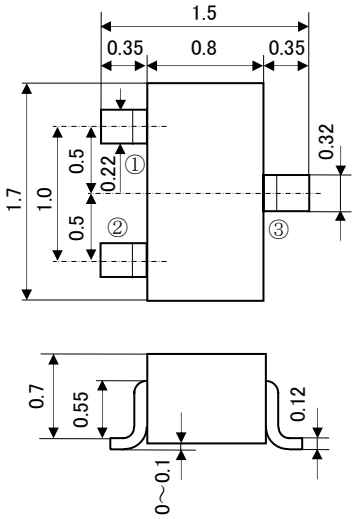
RT1N150C



JEITA : SC-59
JEDEC : Similar to TO-236

Terminal Connector
①:Base
②:Emitter
③:Collector

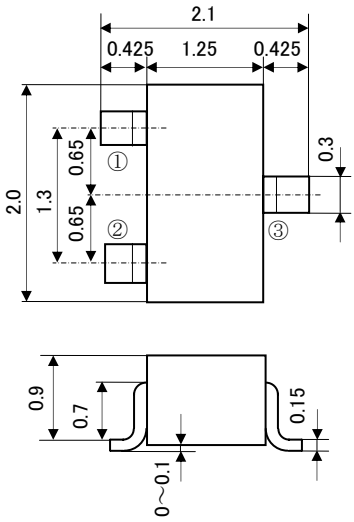
RT1N150U



JEITA : SC-75A
JEDEC : —

Terminal Connector
①:Base
②:Emitter
③:Collector

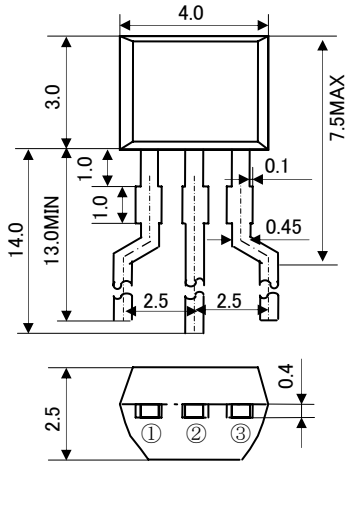
RT1N150M



JEITA : SC-70
JEDEC : —

Terminal Connector
①:Base
②:Emitter
③:Collector

RT1N150S



JEITA : —
JEDEC : —

Terminal Connector
①:Emitter
②:Collector
③:Base

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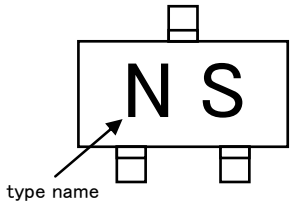
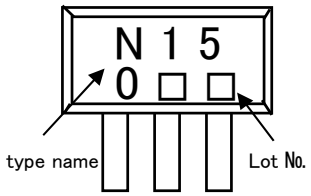
Silicon NPN Epitaxial Type

MARKING

RT1N150C RT1N150M RT1N150U	RT1N150S
	

MAXIMUM RATING (Ta=25℃)

SYMBOL	PARAMETER	RATING				UNIT
		RT1N150U	RT1N150M	RT1N150C	RT1N150S	
V_{CBO}	Collector to Base voltage	50				V
V_{EBO}	Emitter to Base voltage	6				V
V_{CEO}	Collector to Emitter voltage	50				V
I_C	Collector current	100				mA
I_{CM}	Peak Collector current	200				mA
P_C	Collector dissipation(Ta=25℃)	150	200		450	mW
Tj	Junction temperature	+150				℃
Tstg	Storage temperature	−55～+150				℃

ELECTRICAL CHARACTERISTICS (Ta=25℃)

SYMBOL	PARAMETER	TEST CONDITION	LIMIT			UNIT
			MIN	TYP	MAX	
$V_{(BR)CEO}$	C to E break down voltage	I_C=100μA, R_{BE}=∞	50	—	—	V
I_{CBO}	Collector cut off current	V_{CB}=50V, I_E=0	—	—	0.1	μA
I_{EBO}	Emitter cut off current	V_{EB}=5V, I_C=0	—	—	0.1	μA
h_{FE}	DC forward current gain	V_{CE}=5V, I_C=1mA	100	—	—	—
$V_{CE(sat)}$	C to E saturation voltage	I_C=1mA, I_B=0.1mA	—	—	0.3	V
R_1	Input resistor	—	—	100	—	kΩ
f_T	Gain band width product	V_{CE}=6V, I_E=−10mA	—	200	—	MHz

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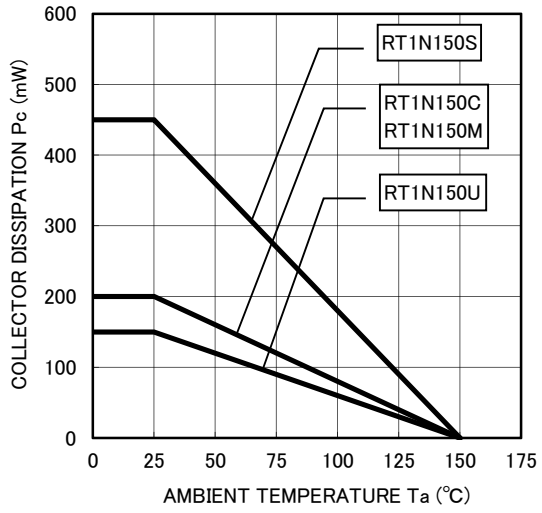
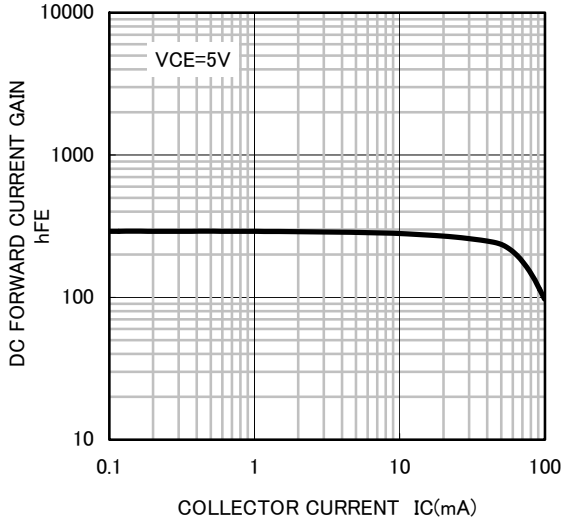
TYPICAL CHARACTERISTICS (Ta=25℃)

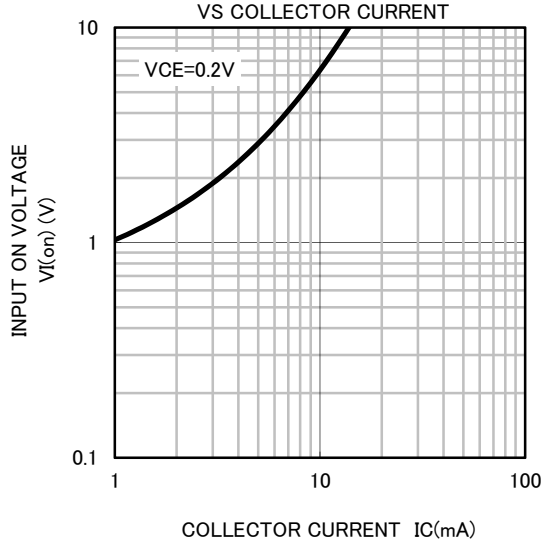
COLLECTOR DISSIPATION
VS AMBIENT TEMPERATURE



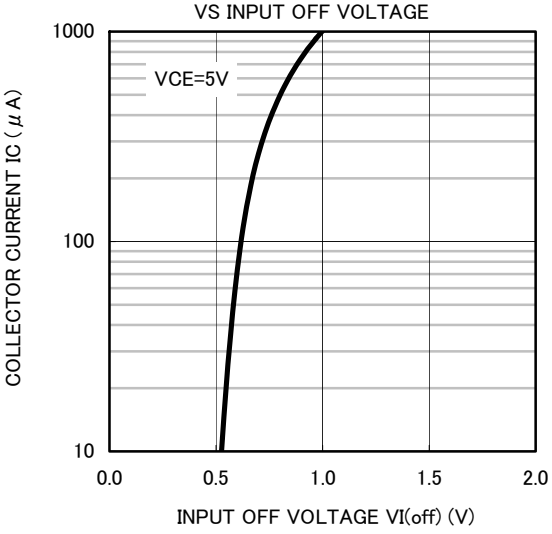
DC FORWARD CURRENT GAIN
VS COLLECTOR CURRENT



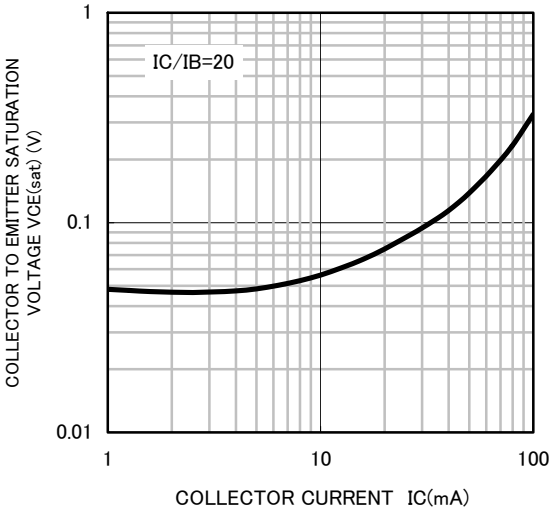
INPUT ON VOLTAGE
VS COLLECTOR CURRENT



COLLECTOR CURRENT
VS INPUT OFF VOLTAGE



COLLECTOR TO EMITTER SATURATION
VOLTAGE VS COLLECTOR CURRENT



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